

International
IR Rectifier

ST330C..C SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

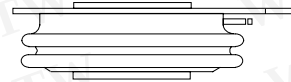
Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)

720A

Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers



case style TO-200AB (E-PUK)

Major Ratings and Characteristics

Parameters	ST330C..C	Units
$I_{T(AV)}$	720	A
@ T_{hs}	55	°C
$I_{T(RMS)}$	1420	A
@ T_{hs}	25	°C
I_{TSM}	@ 50Hz	9000
	@ 60Hz	9420
I^2t	@ 50Hz	405
	@ 60Hz	370
V_{DRM}/V_{RRM}	400 to 1600	V
t_q typical	100	μs
T_J	- 40 to 125	°C

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ST330C..C Series

Bulletin I25155 rev. D 04/03

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IRF Rectifier**ELECTRICAL SPECIFICATIONS****Voltage Ratings**

Type number	Voltage Code	V_{DRM}/V_{RRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_J = T_J \text{ max}$ mA
ST330C..C	04	400	500	50
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

On-state Conduction

Parameter	ST330C..C	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	720 (350)	A	180° conduction, half sine wave double side (single side) cooled
	55 (75)	°C	
$I_{T(RMS)}$ Max. RMS on-state current	1420		DC @ 25°C heatsink temperature double side cooled
I_{TSM} Max. peak, one-cycle non-repetitive surge current	9000	A	t = 10ms No voltage
	9420		t = 8.3ms reapplied
	7570		t = 10ms 100% V_{RRM}
	7920		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	405	KA ² s	t = 10ms No voltage
	370		t = 8.3ms reapplied
	287		t = 10ms 100% V_{RRM}
	262		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	4050	KA ² √s	t = 0.1 to 10ms, no voltage reapplied
$V_{T(TO)1}$ Low level value of threshold voltage	0.91	V	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
$V_{T(TO)2}$ High level value of threshold voltage	0.92		$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
r_{t1} Low level value of on-state slope resistance	0.58	mΩ	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
r_{t2} High level value of on-state slope resistance	0.57		$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ max.}$
V_{TM} Max. on-state voltage	1.96	V	$I_{pk} = 1810A, T_J = T_J \text{ max, } t_p = 10ms \text{ sine pulse}$
I_H Maximum holding current	600	mA	$T_J = 25^\circ\text{C}$, anode supply 12V resistive load
I_L Typical latching current	1000		

Switching

Parameter	ST330C..C	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/μs	Gate drive 20V, 20Ω, $t_r \leq 1\mu s$ $T_J = T_J \text{ max}$, anode voltage $\leq 80\% V_{DRM}$
t_d Typical delay time	1.0	μs	Gate current 1A, $di_g/dt = 1A/\mu s$ $V_d = 0.67\% V_{DRM}, T_J = 25^\circ\text{C}$
t_q Typical turn-off time	100		$I_{TM} = 550A, T_J = T_J \text{ max, } di/dt = 40A/\mu s, V_R = 50V$ $dv/dt = 20V/\mu s$, Gate 0V 100Ω, $t_p = 500\mu s$

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Blocking

Parameter	ST330C..C	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ μ s	$T_J = T_J$ max. linear to 80% rated V_{DRM}
I_{RRM} I_{DRM} Max. peak reverse and off-state leakage current	50	mA	$T_J = T_J$ max, rated V_{DRM}/V_{RRM} applied

Triggering

Parameter		ST330C..C		Units	Conditions	
P _{GM}	Maximum peak gate power	10.0		W	T _J = T _J max, t _p ≤ 5ms	
P _{G(AV)}	Maximum average gate power	2.0			T _J = T _J max, f = 50Hz, d% = 50	
I _{GM}	Max. peak positive gate current	3.0		A	T _J = T _J max, t _p ≤ 5ms	
+V _{GM}	Maximum peak positive gate voltage	20		V	T _J = T _J max, t _p ≤ 5ms	
-V _{GM}	Maximum peak negative gate voltage	5.0				
I _{GT}	DC gate current required to trigger	TYP.	MAX.	mA	Max. required gate trigger/ current/ voltage are the lowest value which will trigger all units 12V anode-to-cathode applied	
		200	-			
		100	200			
		50	-			
V _{GT}	DC gate voltage required to trigger	2.5	-	V		T _J = - 40°C
		1.8	3.0			T _J = 25°C
		1.1	-		T _J = 125°C	
I _{GD}	DC gate current not to trigger	10		mA	Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated V _{DRM} anode-to-cathode applied	
V _{GD}	DC gate voltage not to trigger	0.25				V

Thermal and Mechanical Specification

Parameter	ST330C..C	Units	Conditions
T_J Max. operating temperature range	-40 to 125	$^\circ\text{C}$	
T_{stg} Max. storage temperature range	-40 to 150		
R_{thJ-hs} Max. thermal resistance, junction to heatsink	0.09 0.04	K/W	DC operation single side cooled DC operation double side cooled
R_{thC-hs} Max. thermal resistance, case to heatsink	0.02 0.01	K/W	DC operation single side cooled DC operation double side cooled
F Mounting force, $\pm 10\%$	9800 (1000)	N (Kg)	
wt Approximate weight	83	g	
Case style	TO-200AB (E-PUK)		See Outline Table

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ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.012	0.011	0.008	0.007	K/W	$T_j = T_j \text{ max.}$
120°	0.014	0.012	0.014	0.013		
90°	0.017	0.015	0.019	0.017		
60°	0.025	0.022	0.026	0.023		
30°	0.043	0.036	0.043	0.037		

Ordering Information Table

Device Code							
ST	33	0	C	16	C	1	
①	②	③	④	⑤	⑥	⑦	⑧
1	Thyristor						
2	Essential part number						
3	0 = Converter grade						
4	C = Ceramic Puk						
5	Voltage code: Code x 100 = V_{RRM} (See Voltage Rating Table)						
6	C = Puk Case TO-200AB (E-PUK)						
7	0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads) 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads) 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads) 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)						
8	Critical dv/dt: None = 500V/ μ sec (Standard selection) L = 1000V/ μ sec (Special selection)						

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Outline Table

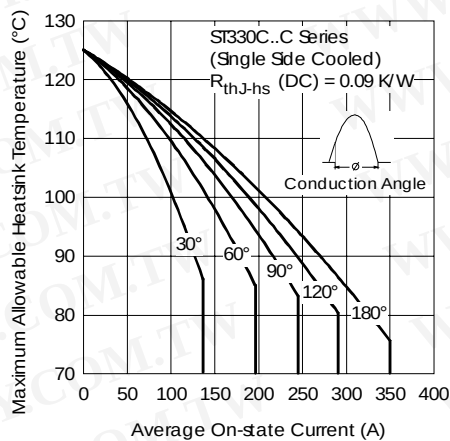
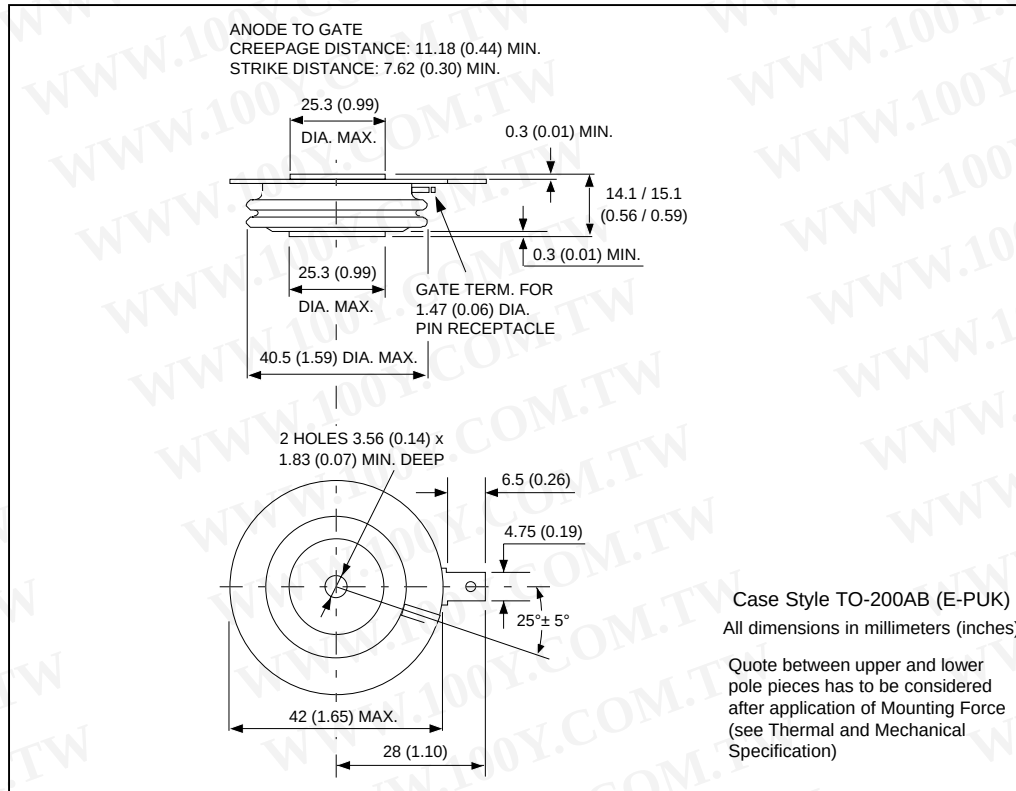


Fig. 1 - Current Ratings Characteristics

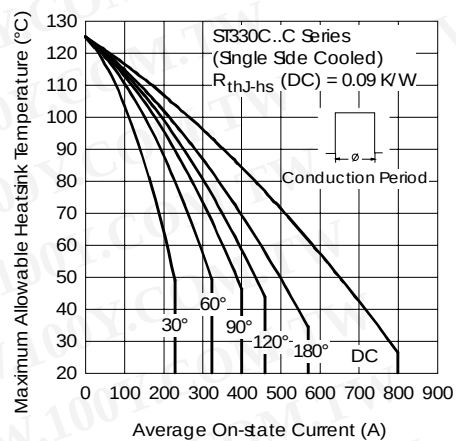


Fig. 2 - Current Ratings Characteristics

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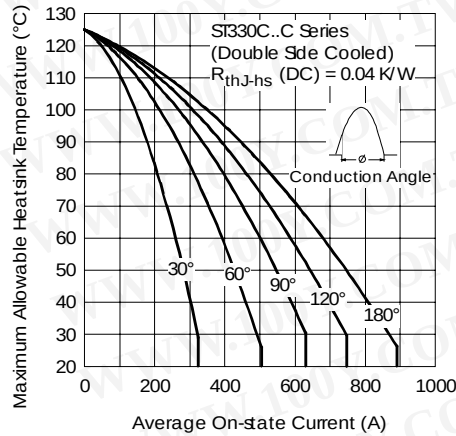


Fig. 3 - Current Ratings Characteristics

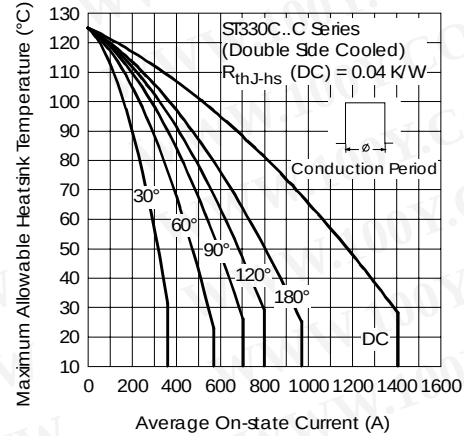


Fig. 4 - Current Ratings Characteristics

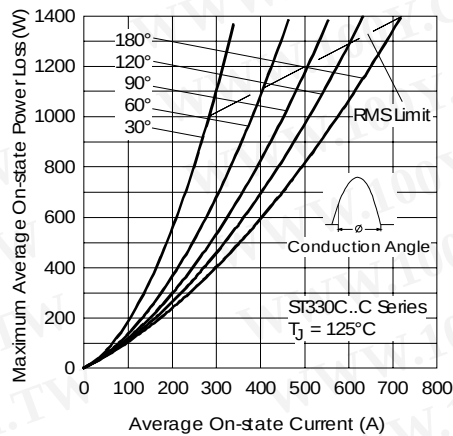


Fig. 5 - On-state Power Loss Characteristics

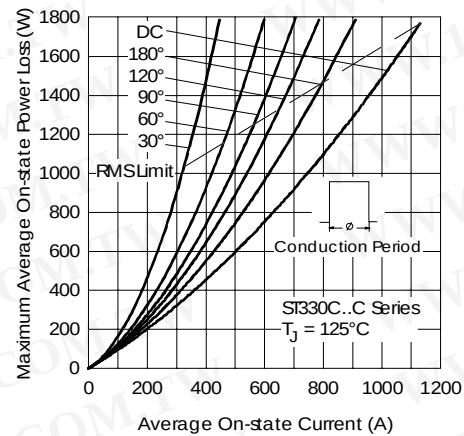


Fig. 6 - On-state Power Loss Characteristics

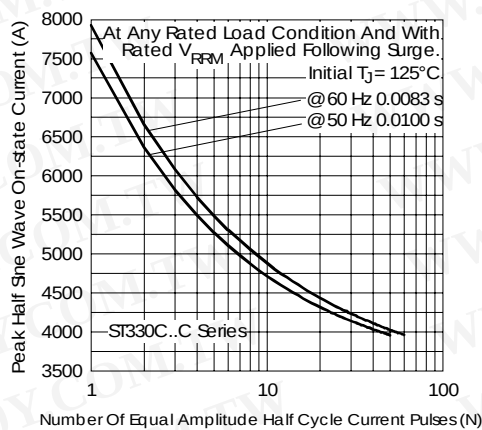


Fig. 7 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

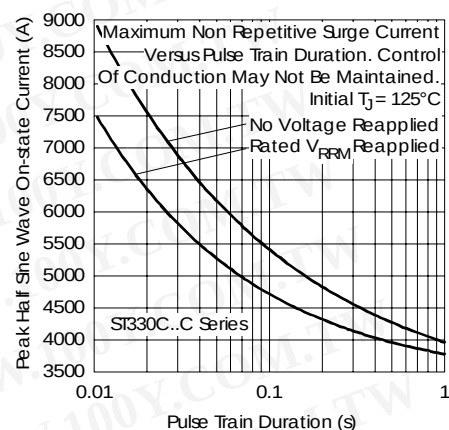


Fig. 8 - Maximum Non-Repetitive Surge Current
Single and Double Side Cooled

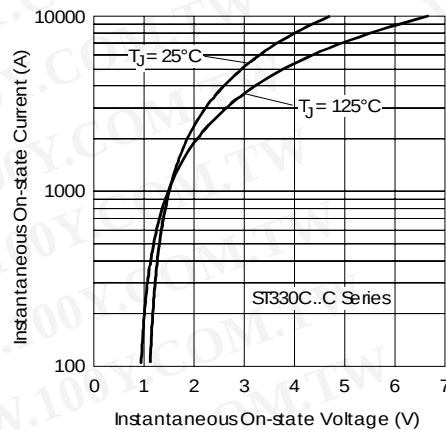


Fig. 9 - On-state Voltage Drop Characteristics

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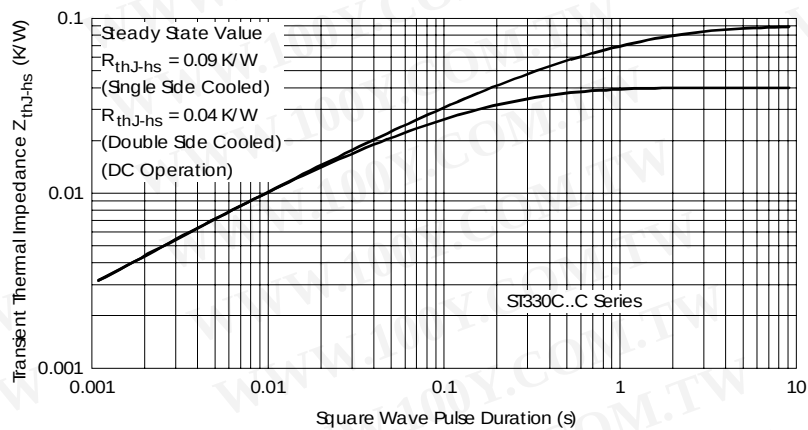


Fig. 10 - Thermal Impedance Z_{thj-hs} Characteristics

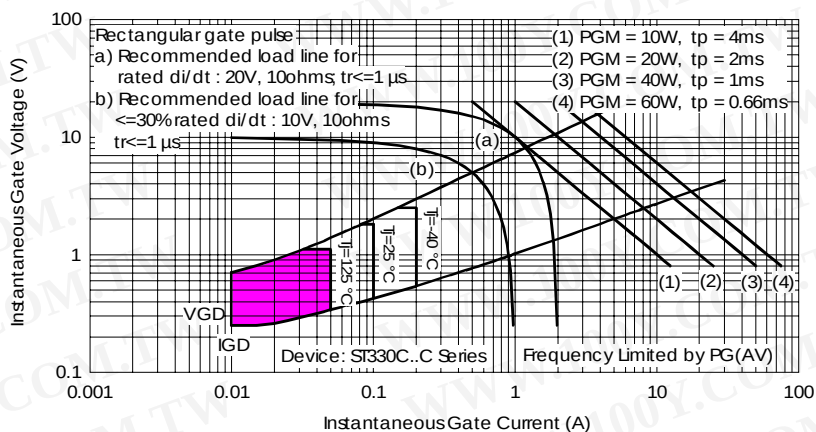


Fig. 11 - Gate Characteristics

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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